



60V PNP SMALL SIGNAL TRANSISTOR IN SOT523

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of automotive applications.

Features

- BV_{CEO} > -60V
- I_C = -150mA Collector Current
- Ultra-Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The 2DA1774QQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

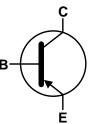
Mechanical Data

- Package: SOT523
- Package Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.002 grams (Approximate)

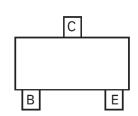
SOT523



Top View



Device Symbol



Pin-Out Top View

Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
2DA1774QQ-7	Automotive	8A	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SOT523



 $8A = Product Type Marking Code \\ YM = Date Code Marking \\ Y or <math>\overline{Y} = Year \ (ex: I = 2021) \\ M \ or \ \overline{M} = Month \ (ex: 9 = September)$

Date Code Key

Year	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code	ı	J	K	L	М	N	0	Р	R	S	Т	U
Month	lan	Feb	Mar	Amr	Mav	lum	Jul	Aug	Sep	Oct	Nov	Dec
WOITH	Jan	reb	iviai	Apr	iviay	Jun	Jui	Aug	ОСР	OCI	1404	DCC
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-60	V
Collector-Emitter Voltage	V _{CEO}	-50	V
Emitter-Base Voltage	V _{EBO}	-6.0	V
Collector Current - Continuous (Note 5)	Ic	150	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5) T _A = +25°C	P_D	150	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ heta JA}$	833	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

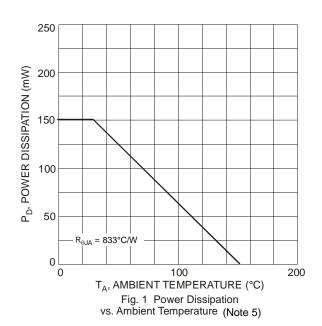
ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information



^{5.} For a device mounted with the collector lead on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.

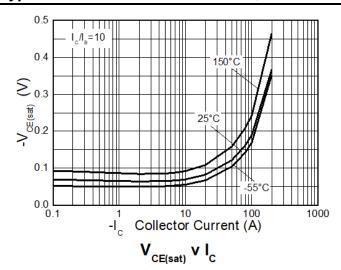


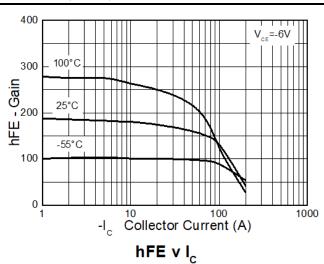
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

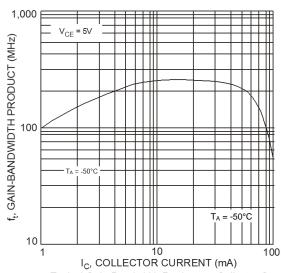
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)		•				
Collector-Base Breakdown Voltage	BV _{CBO}	-60	_		V	$I_C = -50\mu A$
Collector-Emitter Breakdown Voltage	BV _{CEO}	-50	_		V	$I_C = -1mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	-6.0	_	_	V	I _E = -50μA
Collector Cutoff Current	I _{CBO}	_	_	-100	nA	V _{CB} = -60V
Emitter Cutoff Current	I _{EBO}	_	_	-100	nA	V _{EB} = -6V
ON CHARACTERISTICS (Note 7)						
DC Current Gain	h _{FE}	120		270	_	$V_{CE} = -6V$, $I_{C} = -1mA$
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	_	-0.5	V	$I_C = -50 \text{mA}, I_B = -5 \text{mA}$
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C_{obo}	_	4.0	5.0	pF	$V_{CB} = -12V$, $f = 1.0MHz$, $I_E = 0$
Current Gain-Bandwidth Product	f _t	_	140		MHz	$V_{CE} = -12V$, $I_C = -2mA$, $f = 30MHz$

Notes: 7. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)





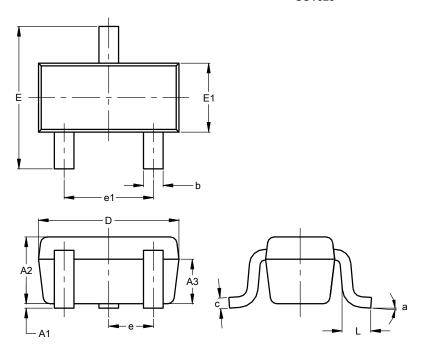




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523

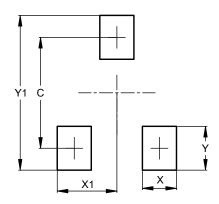


SOT523							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.60	0.80	0.75				
A3	0.45	0.65	0.50				
b	0.15	0.30	0.22				
С	0.10	0.20	0.12				
D	1.50	1.70	1.60				
E	1.45	1.75	1.60				
E1	0.75	0.85	0.80				
е	0.50 BSC						
e1	0.90	1.10	1.00				
L	0.20	0.40	0.33				
а	0°		8°				
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523



Dimensions	Value			
Dilliciisions	(in mm)			
С	1.29			
X	0.40			
X1	0.70			
Y	0.51			
Y1	1.80			



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